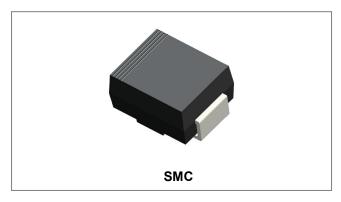






FR3A-FR3M 3.0A SURFACE MOUNT FAST RECOVERY RECTIFIER



Features

- Fast switching for high efficiency
- Low leakage current
- · High forward surge capability
- Solder dip 260° C, 40s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- Glass passivated chip junction
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

Case: SMC molded plastic

- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: AnyWeight: 0.21grams

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic	Symbol	FR3A	FR3B	FR3D	FR3G	FR3J	FR3K	FR3M	Units
Peak Repetitive Reverse Voltage DC Blocking Voltage	V _{RRM} V _{DC}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Average forward rectified output current @T _A = 75°C	I _(AV)	3.0			А				
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	100			А				
Forward Voltage @I _F =3.0A	V_{FM}	1.30			V				
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}	5.0 50.0			μA				
Reverse recovery time (Note 1)	t _{rr}	150 250 500		00	ns				
Typical Junction Capacitance (Note 2)		60					pF		
Typical Thermal Resistance (Note 3)	R _{θJA}	R _{ejA} 50			°C/W				
Operating and Storage Temperature Range	T _{STG}	-55 to +150				°C			

Note: 1. Reverse recovery condition IF=0.5A, IR=1.0A, Irr=0.25A

- 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
- 3. Mounted on P.C.B Board with 8.0mm² land area.
 - China Germany Korea Singapore United States •
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 sales@ smc-diodes.com







Ratings and Characteristics Curves

FIG.1-FORWARD CURRENT DERATING CURVE

AVERAGE FORWARD RECTIFIED CURRENT

Single Phase

1.2

Single Phase

Both age to the companient of the

INSTANTANEOUS FORWARD CURRENT, AMPERES

AMBIENT TEMPERATURE, °C

125

150

175

FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

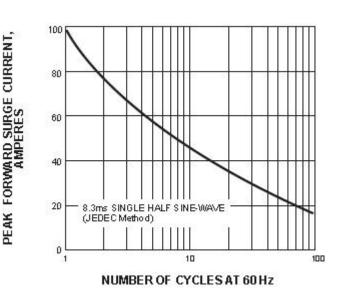
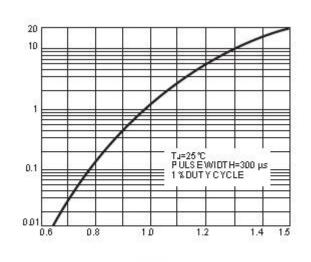
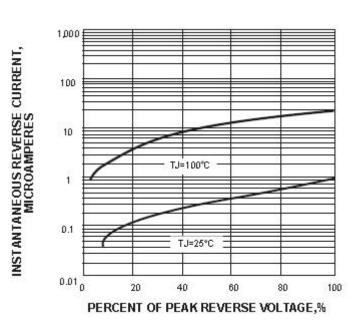


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.4-TYPICAL REVERSE CHARACTERISTICS



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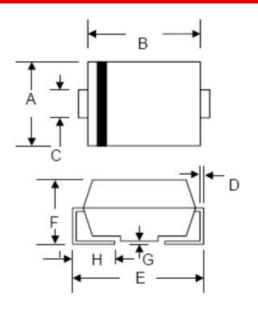
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Mechanical Dimensions SMC



SYMBOL	Millir	neters	Inches		
STIVIBUL	Min. Max.		Min.	Max.	
А	5.59	6.22	0.220	0.245	
В	6.60	7.11	0.260	0.280	
С	2.75	3.25	0.108	0.128	
D	0.152	0.305	0.006	0.012	
E	7.75	8.25	0.305	0.325	
F	2.00	2.95	0.079	0.116	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.60	0.030	0.063	

Ordering Information

Device	Package	Shipping		
FR3A-FR3M	SMC	3000pcs / reel		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

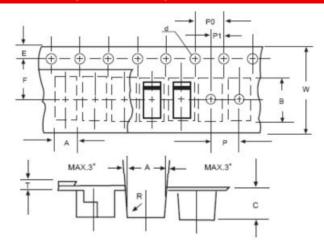


Where XXXXX is YYWWL

FR3A = Part Name
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape & Reel Specification SMC



SYMBOL	Millimeters			
STIVIBUL	Min.	Max.		
Α	5.90	6.10		
В	8.20	8.40		
С	2.40	2.60		
d	1.40	1.60		
E	1.40	1.60		
F	7.60	7.70		
Р	7.90	8.10		
P0	3.90	4.10		
P1	3.90	4.10		
T	-	0.600		
W	15.80	16.20		

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